

# MM54HC192/MM74HC192 Synchronous Decade Up/Down Counters MM54HC193/MM74HC193 Synchronous Binary Up/Down Counters

# **General Description**

These high speed synchronous counters utilize advanced silicon-gate CMOS technology to achieve the high noise immunity and low power consumption of CMOS technology, along with the speeds of low power Schottky TTL. The MM54HC192/MM74HC192 is a decade counter, and the MM54HC193/MM74HC193 is a binary counter. Both counters have two separate clock inputs, an UP COUNT input and a DOWN COUNT input. All outputs of the flip-flops are simultaneously triggered on the low to high transition of either clock while the other input is held high. The direction of counting is determined by which input is clocked.

These counters may be preset by entering the desired data on the DATA A, DATA B, DATA C, and DATA D inputs. When the LOAD input is taken low the data is loaded independently of either clock input. This feature allows the counters to be used as divide-by-n counters by modifying the count length with the preset inputs.

In addition both counters can also be cleared. This is accomplished by inputting a high on the CLEAR input. All 4 internal stages are set to a low level independently of either COUNT input.

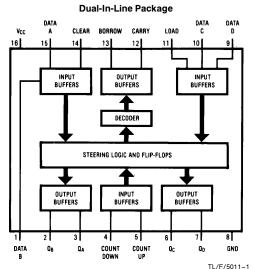
Both a BORROW and CARRY output are provided to enable cascading of both up and down counting functions. The BORROW output produces a negative going pulse when the counter underflows and the CARRY outputs a pulse when the counter overflows. The counters can be cascaded by connecting the CARRY and BORROW outputs of one device to the COUNT UP and COUNT DOWN inputs, respectively, of the next device.

All inputs are protected from damage due to static discharge by diodes to  $\ensuremath{V_{CC}}$  and ground.

#### **Features**

- Typical propagation delay, Count up to Q: 28 ns
- Typical operating frequency: 27 MHz
- Wide power supply range: 2-6V
- Low quiescent supply current: 80 μA maximum (74HC Series)
- Low input current: 1  $\mu$ A maximum
- 4 mA output drive

## **Connection Diagram**



Order Number MM54HC192/193 or MM74HC192/193

## **Truth Table**

Count		Clear	Load	Function	
Up	Down	Olcai	Load	- anotion	
1	Н	L	Н	Count Up	
Н	↑	L	Н	Count Down	
X	Х	Н	Х	Clear	
X	X	L	L	Load	

H = high level

L = low level

 $\uparrow$  = transition from low-to-high

X = don't care

# Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.5 to $+7.0$ V
DC Input Voltage (V <sub>IN</sub> )	$-1.5$ to $V_{CC} + 1.5V$
DC Output Voltage (V <sub>OUT</sub> )	$-0.5$ to $V_{CC} + 0.5V$
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	$\pm$ 20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	$\pm$ 25 mA
DC V <sub>CC</sub> or GND Current, per pin (I <sub>CC</sub> )	$\pm$ 50 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C

Power Dissipation (PD)

(Note 3) 600 mW S.O. Package only 500 mW 260°C

Lead Temp. ( $T_L$ ) (Soldering 10 seconds)

<b>Operating Conditi</b>	Operating Conditions										
	Min	Max	Units								
Supply Voltage (V <sub>CC</sub> )	2	6	V								
DC Input or Output Voltage $(V_{IN}, V_{OUT})$	0	$V_{CC}$	V								
Operating Temp. Range (T <sub>A</sub> )											
MM74HC	-40	+85	°C								
MM54HC	-55	+125	°C								
Input Rise or Fall Times											
$(t_r, t_f)$ $V_{CC} = 2V$		1000	ns								
$V_{CC} = 4.5V$		500	ns								
$V_{CC} = 6.0V$		400	ns								

# **DC Electrical Characteristics** (Note 4)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = 25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> = -55 to 125°C	Units
				Тур		Guaranteed	Limits	
V <sub>IH</sub>	Minimum High Level Input Voltage		2.0V 4.5V 6.0V		1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V V V
V <sub>IL</sub>	Maximum Low Level Input Voltage**		2.0V 4.5V 6.0V		0.5 1.35 1.8	0.5 1.35 1.8	0.5 1.35 1.8	V V
V <sub>OH</sub>	Minimum High Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 20 \mu A$	2.0V 4.5V 6.0V	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V V V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 4.0 \text{ mA}$ $ I_{OUT}  \le 5.2 \text{ mA}$	4.5V 6.0V	4.2 5.7	3.98 5.48	3.84 5.34	3.7 5.2	V V
V <sub>OL</sub>	Maximum Low Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 20 \mu A$	2.0V 4.5V 6.0V	0 0 0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V V V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 4.0 \text{ mA}$ $ I_{OUT}  \le 5.2 \text{ mA}$	4.5V 6.0V	0.2 0.2	0.26 0.26	0.33 0.33	0.4 0.4	V V
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	±1.0	μΑ
Icc	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu A$	6.0V		8.0	80	160	μΑ

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages ( $V_{OH}$ , and  $V_{OL}$ ) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case  $V_{IH}$  and  $V_{IL}$  occur at  $V_{CC}$ =5.5V and 4.5V respectively. (The  $V_{IH}$  value at 5.5V is 3.85V.) The worst case leakage current ( $I_{IN}$ ,  $I_{CC}$ , and  $I_{OZ}$ ) occur for CMOS at the higher voltage and so the 6.0V values should be used.

<sup>\*\*</sup> $V_{IL}$  limits are currently tested at 20% of  $V_{CC}$ . The above  $V_{IL}$  specification (30% of  $V_{CC}$ ) will be implemented no later than Q1, CY'89.

$\Delta I_{\star}$ FIRCH CALCALLATION CONTROL TABLE $\Delta I_{\star} = 25^{\circ} \text{C}$ $V_{00} = 5 \text{ DV}$ $t_{\star} = t_{\star} = 6 \text{ ns}$ $C_{\star} = 15 \text{ nF}$ (unless otherwise specific	se specified)	= 25°C, $V_{CC} = 5.0V$ , $t_r = t_r = 6$ ns, $C_1 = 15$ nF (unless otherwise	Characteristics :	AC Flectrical
--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------	---------------	-------------------------------------------------------------------------------	-------------------	---------------

Symbol	Parameter	Conditions		Тур	Guaranteed Limit	Units
f <sub>MAX</sub>	Maximum Clock Frequency	Count Up	27	20	MHz	
'MAX	Waximum clock r requeries	Count Down	Count Down			MHz
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Count Up to Carry	17	26	ns	
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Count op to carry	18	24	ns	
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Count Down to	16	24	ns	
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Borrow	15	24	ns	
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Count Up Or		28	40	ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Down to Q	36	52	ns	
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Data or Load to Q		30	42	ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Load to Q	40	55	ns	
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Clear to Q	Clear to Q		47	ns
		Clear	'HC192 'HC193	40 20	52 26	ns ns
$t_{W}$	Minimum Pulse Width	Load	'HC192 'HC193	40 10	52 20	ns ns
		Count Up/Down	15	22	ns	
t <sub>SD</sub>	Minimum Setup time	Data to Load		10	20	ns
t <sub>HD</sub>	Minimum Hold Time	Dala lo Loau		-3	0	ns
t <sub>REM</sub>	Minimum Removal Time	Clear Inactive to Clock			10	ns

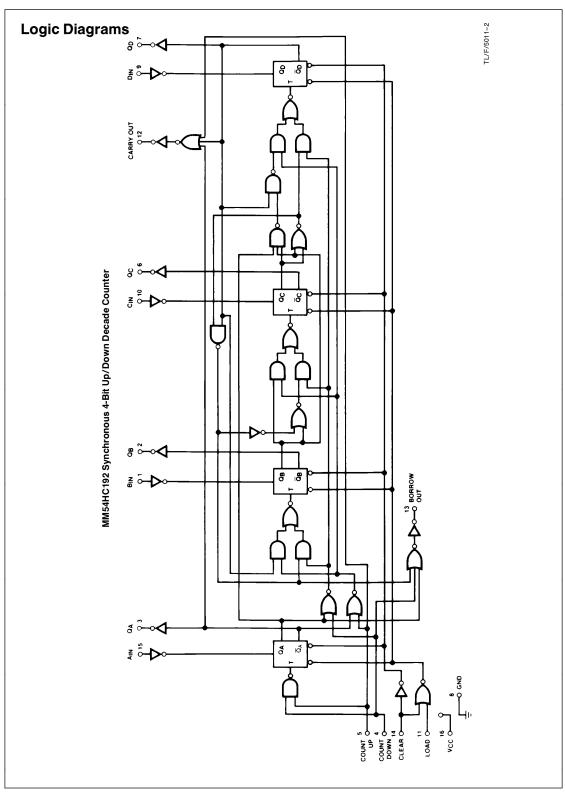
# AC Electrical Characteristics $V_{CC} = 2.0V \text{ to } 6.0V, C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns}$

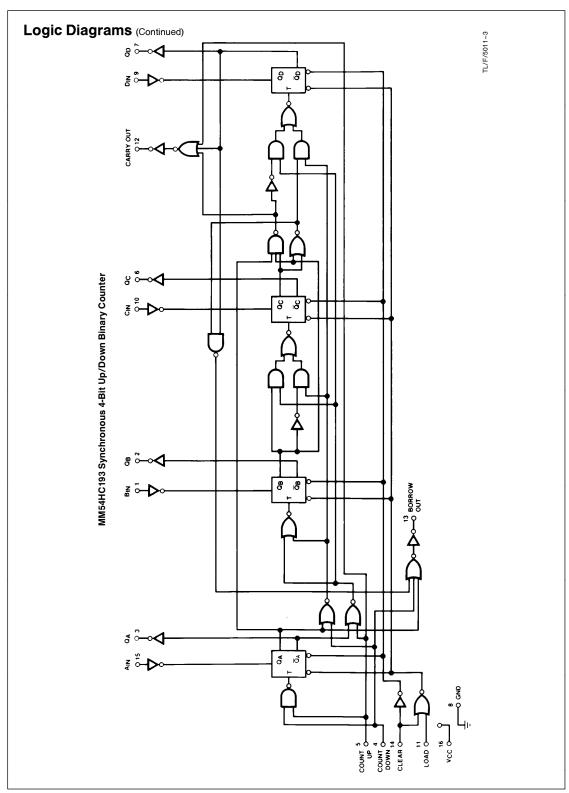
Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> =25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> = -55 to 125°C	Units
				Тур		Guaranteed		
		Count Up	2.0V 4.5V	5 25	3 18	2.5 14	2 12	MHz MHz
f <sub>MAX</sub>	Maximum Clock Frequency	Count Down	6.0V 2.0V 4.5V 6.0V	29 5 27 31	20 4 20 23	16 3 16 18	13 2 11 12	MHz MHz MHz MHz
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Count Up	2.0V 4.5V 6.0V	30 13 11	140 28 24	175 35 30	210 42 36	ns ns ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	to Carry	2.0V 4.5V 6.0V	39 16 14	130 26 22	163 33 28	195 39 33	ns ns ns

AC Electrical Characteristics (Continued)  $V_{CC}=2.0V$  to 6.0V,  $C_L=50~pF,\,t_r=t_f=6~ns$ 

Symbol	Parameter	Con	Conditions		T <sub>A</sub> =25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> = -55 to 125°C	Units
					Тур		Guaranteed	Limits	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay		Count Down to Borrow		39 16 14	130 26 22	163 33 28	195 39 33	ns ns ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Rise and Fall Time				30 8 7	75 15 13	95 19 16	110 22 19	ns ns ns
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Coun	Count Up Or Down to Q		77 35 30	215 43 37	269 54 46	323 65 55	ns ns ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Down to			95 45 38	275 55 47	344 69 59	413 83 71	ns ns ns
t <sub>PLH</sub>	Maximum Propagation Delay Low to High	Data or	Data or Load to Q		85 37 30	230 46 39	288 58 49	345 69 59	ns ns ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Load to			102 47 39	290 58 49	363 73 61	435 87 74	ns ns ns
t <sub>PHL</sub>	Maximum Propagation Delay High to Low	Clear to	Clear to Q		85 42 38	265 53 45	331 66 56	398 80 68	ns ns ns
		Clear or Load	'HC192	2.0V 4.5V 6.0V	119 42 38	260 52 45	325 65 56	390 78 68	ns ns ns
t <sub>W</sub>	Minimum Pulse Width	Load	'HC193	2.0V 4.5V 6.0V	31 10 9	100 20 17	125 25 21	150 30 26	ns ns ns
		Count	Count Up/Down		43 17 15	110 22 19	138 28 24	165 33 29	ns ns ns
		Clear	Clear 'HC193		70 21 19	130 26 22	163 33 28	195 39 33	ns ns ns
t <sub>SD</sub>	Minimum Setup Time	Data	Data -To Load		30 10 9	100 20 17	125 25 22	150 30 25	ns ns ns
t <sub>HD</sub>	Minimum Hold Time				-30 -3	0 0 0	0 0 0	0 0 0	ns ns ns
t <sub>REM</sub>	Minimum Removal Time		Clear Inactive to Clock		-20 -3 -2	10 10 10	10 10 10	10 10 10	ns ns ns
t <sub>r</sub> , t <sub>f</sub>	Maximum Count Up or Down Input Rise & Fall Time					500 300 200	500 300 200	500 300 200	ns ns ns
C <sub>IN</sub>	Input Capacitance				5	10	10	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note	5)			100				pF

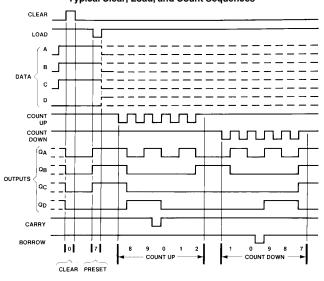
Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC} \ V_{CC}$ .





# **Logic Waveforms**

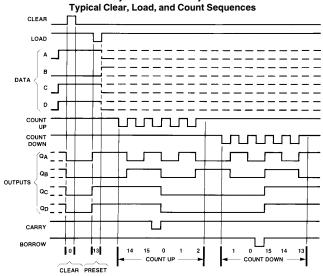
### 'HC192 Synchronous Decade Counters Typical Clear, Load, and Count Sequences



TL/F/5011-4

- Sequences:
  (1) Clear outputs to zero
  (2) Load (preset) to BCD seven.
  (3) Count up to eight, nine, carry, zero, one and two.
- (4) Count down to one, zero, borrow, nine, eight, and seven.

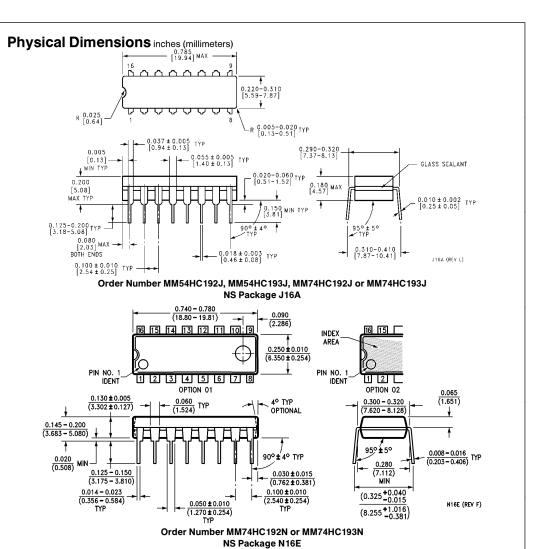
# 'HC193 Synchronous Binary Counters



TL/F/5011-5

- Sequence: (1) Clear outputs to zero.
- (2) Load (preset) to binary thirteen
- (3) Count up to fourteen, fifteen, carry, zero, one, and two.
   (4) Count down to one, zero, borrow, fifteen, fourteen, and thirteen.
   Note A: Clear overrides load data, and count inputs.

Note B: When counting up, count-down input must be high; when counting down, count-up input must be high.



#### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor

National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

**National Semiconductor** Europe

Fax: (+49) 0-180-530 85 86 Fax: (+49) 0-180-350 op ov Email: onjwge@tevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tel: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 58 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408